



Type 2N3019S
Geometry 4500
Polarity NPN
Qual Level: JAN - JANS

Generic Part Number: 2N3019

REF: MIL-PRF-19500/391

## Features:

 General-purpose transistor for switching and amplifier applicatons.

- Housed in a TO-39 case.
- Also available in chip form using the 4500 chip geometry.
- The Min and Max limits shown are per MIL-PRF-19500/391 which Semicoa meets in all cases.

· Radiation Graphs available

**Request Quotation** 



**Maximum Ratings** 

 $T_C = 25^{\circ}C$  unless otherwise specified

Rating	Symbol	Rating	Unit		
Collector-Emitter Voltage	V <sub>CEO</sub>	80	V		
Collector-Base Voltage	V <sub>CBO</sub>	140	V		
Emitter-Base Voltage	V <sub>EBO</sub>	7.0	V		
Collector Current, Continuous	I <sub>C</sub>	1.0	mA		
Operating Junction Temperature	TJ	-55 to +175	°C		
Storage Temperature	T <sub>STG</sub>	-55 to +175	°C		



## **Electrical Characteristics**

 $T_C = 25^{\circ}C$  unless otherwise specified

<b>OFF Characteristics</b>	Symbol	Min	Max	Unit
Collector-Base Breakdown Voltage $I_C = 100 \ \mu A$	V <sub>(BR)CBO</sub>	140		V
Collector-Emitter Breakdown Voltage I <sub>C</sub> = 30 mA	$V_{(BR)CEO}$	80		V
Emitter-Base Breakdown Voltage $I_E = 100 \mu A$	$V_{(BR)EBO}$	7.0		V
Collector-Emitter Cutoff Current $V_{CE} = 90 \text{ V}$	I <sub>CES</sub>		10	nA
Emitter-Base Cutoff Current $V_{EB} = 5 \text{ V}$	I <sub>EBO</sub>		10	nA

ON Characteristics	Symbol	Min	Max	Unit
DC Current Gain		4	ear-	
$I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$	h <sub>FE1</sub>	100	300	
$I_C = 0.1 \text{ mA}, V_{CE} = 10 \text{ V}$	h <sub>FE2</sub>	50 🥑	200	
$I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V (pulse test)}$	h <sub>FE3</sub>	90		
$I_C$ = 500 mA, $V_{CE}$ = 10 V (pulse test)	h <sub>FE4</sub>	50	200	
$I_C = 1 \text{ A}, V_{CE} = 10 \text{ V (pulse test)}$	h <sub>FE5</sub>	15		
Collector-Emitter Saturation Voltage				
$I_C = 150 \text{ mA}$ , $I_B = 15 \text{ mA}$ (pulse test)	V <sub>CE(sat)1</sub>		0.2	V dc
$I_C = 500 \text{ mA}$ , $I_B = 50 \text{ mA}$ (pulse test)	V <sub>CE(sat)2</sub>		0.5	V dc
Base-Emitter Saturation Voltage				
$I_C = 150 \text{ mA}, I_B = 15 \text{ mA} \text{ (pulse test)}$	$V_{BE(sat)}$		1.1	V dc

Small Signal Characteristics	Symbol	Min	Max	Unit
Short Circuit Forward Current Transfer Ratio $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$	AC h <sub>FE</sub>	80	400	
Magnitude of Common Emitter Short Circuit Forward Current Transfer Ratio $V_{CE} = 10 \text{ V}, I_{C} = 50 \text{ mA}, f = 200 \text{ MHz}$	h <sub>FE</sub>	5.0	20	
Open Circuit Output Capacitance V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, 100 kHz < f < 1 MHz	C <sub>OBO</sub>		12	pF
Input Capacitance, Output Open Circuited  V <sub>EB</sub> = 2.0 V, I <sub>C</sub> = 0, 100 kHz < f < 1 MHz	C <sub>IBO</sub>		60	pF
Collecor-Base Time Constant $V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}, f = 79.8 \text{ MHz}$	$r_{b'}C_C$		400	ps
Noise Figure $V_{CE} = 10 \text{ V}, I_{C} = 100 \mu\text{A}, R_{g} = 1 \text{ kOhm}$	NF		4	dB

<b>Switching Characteristics</b>	Symbol	Min	Max	Unit
Pulse Response 15 ns, 50 ohm input pulse	t <sub>ON+</sub> t <sub>OFF</sub>		30	ns